

GL8□□4 Series Arch Type 'ED 'amps

■ Model No.

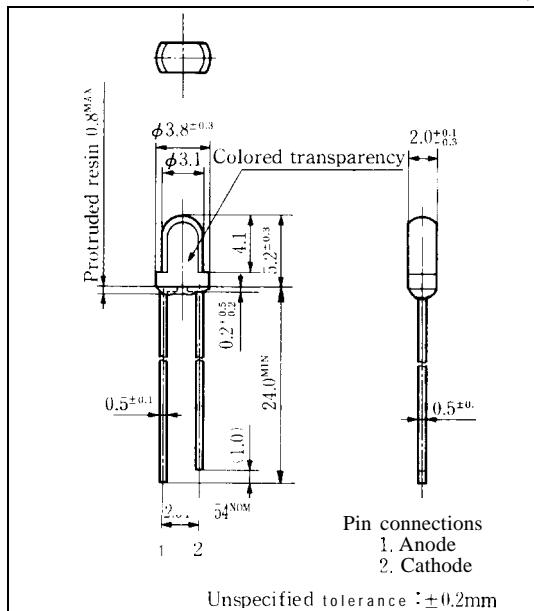
GL8UR4 Red (Super-luminosity)	GaAlAs/GaAlAs
GL8LR4 Red [High-luminosity]	GaAlAs/GaAs
GL8TR4 Red [High-luminosity]	GaAlAs/GaAs
GL8HD4 Red	GaAsP/GaP
GL8HY4 Yellow	GaAsP/GaP
GL8EG4 Yellow-green	GaP

■ Features

1. 2.0mm×3.1mm arch type all resin mold
2. Colored transparency lens type

■ Outline Dimensions

(Unit: mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter	Symbol	GL8UR4	GL8LR4	GL8HD4	GL8EG4	Unit
		GL8TR4	GL8HY4			
Power dissipation	P	75	110	84	84	mW
Continuous forward current	I _F	30	50	30	30	mA
*1 Peak forward current	I _{FM}	50	300	50	50	mA
Derating factor	DC	—	0.40	0.67	0.40	m A/°C
	Pulse		0.67	4.00	0.67	m A/°C
Reverse voltage	V _R	4	5	5	5	V
Operating temperature	T _{opr}		-25 to +85			
Storage temperature	T _{sig}		-25 to +100			
*2 Soldering temperature	T _{sol}		260 (within 5 seconds)			

*1 Duty ratio = 1/10, Pulse width = 0.1ms

Duty ratio = 1/16, Pulse width \leq 1ms for GL8LR4 and GL8TR4

*2 At the position of 1.6mm from the bottom face of resin package

SHARP

GL8UR4 (Red)

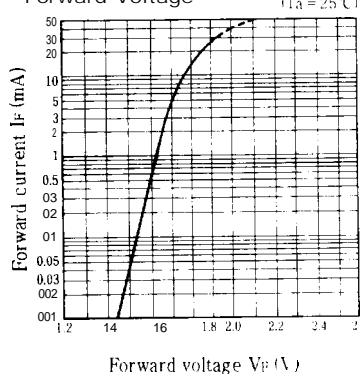
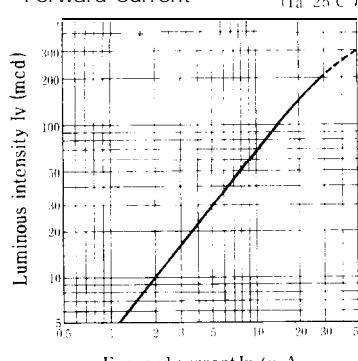
■ Electro-optical Characteristics

(Ta = 25°C)

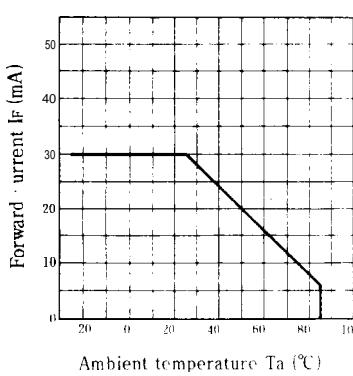
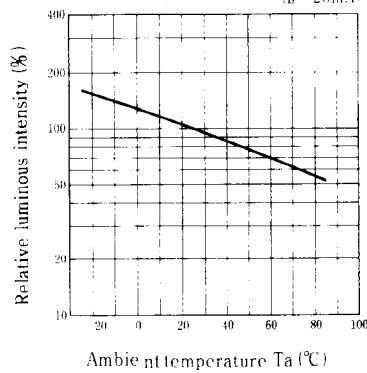
Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8UR4	I _F = 20mA		1.85	2.5	V
*3 Luminous intensity	I _V	GL8UR4	I _F = 20mA	80	150	-	mcd
Peak emission wavelength	λ_p	GL8UR4	I _F = 20mA	-	660	-	nm
Spectrum radiation bandwidth	$\Delta\lambda$	GL8UR4	I _F = 20mA	20	--	--	nm
Reverse current	I _R	GL8UR4	V _R = 3V	-	100	-	μA
Terminal capacitance	C _t	GL8UR4	V = 0V f = 1 MHz	-	25	-	pF
Response frequency	f _c	GL8UR4	-	8	-	-	MHz

*3 Tolerance: $\pm 30\%$

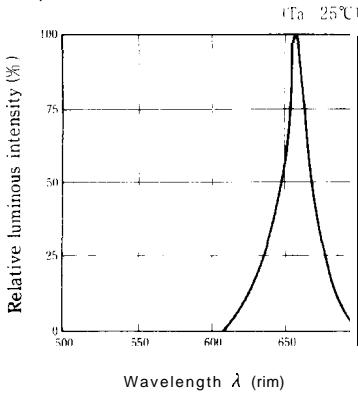
■ Characteristics Diagrams

Forward Current vs.
Forward VoltageLuminous Intensity va.
Forward Current

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature (I_b = 20mA)

Spectrum Distribution



3

GL8LR4 (Red) / GL8TR4 Red

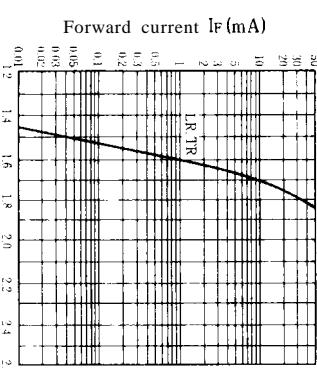
■ Electro-optical Characteristics

Parameter	Symbol	Model No.	Condition	MIN	TYP	MAX	unit
Forward voltage	V_F	GL8LR4 GL8TR4	$I_F = 20\text{mA}$ $I_F = 200\text{mA}$	—	1.45	2.2	V
※ Luminous intensity	I_V	GL8LR4 GL8TR4	$I_F = 20\text{mA}$ $I_F = 200\text{mA}$	25	1V	—	mcd
Peak emission wavelength	λ_p	GL8LR4 GL8TR4	$I_F = 20\text{mA}$ $I_F = 200\text{mA}$	—	650	—	nm
Spectrum radiation bandwidth	$\Delta \lambda$	GL8LR4 GL8TR4	$I_F = 20\text{mA}$ $I_F = 200\text{mA}$	—	20	—	nm
Reverse current	I_R	GL8LR4 GL8TR4	$V_R = 4\text{V}$ $V_R = 20\text{mV}$	—	20	—	μA
Terminal capacitance	C_t	GL8LR4 GL8TR4	$V_F = 0\text{V}$ $I_F = 20\text{mA}$	—	—	10	pF
Response frequency	f_c	—	—	—	x	—	MHz

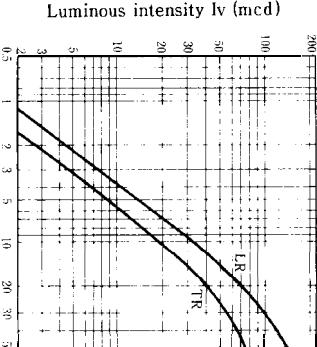
※3 Tolerance: $\pm 30\%$

■ Characteristics Diagrams

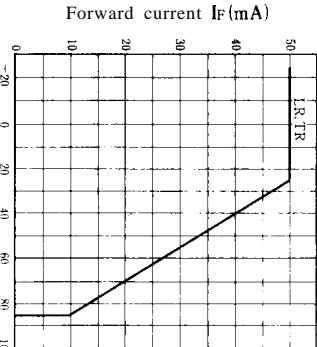
Forward Current vs.
Forward Voltage $(T_a = 25^\circ\text{C})$



Luminous Intensity vs.
Forward Current $(T_a = 25^\circ\text{C})$



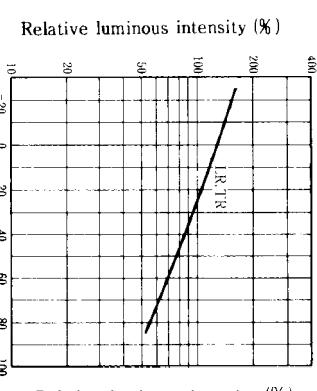
Forward Current Derating Curve $(T_a = 25^\circ\text{C})$



Relative Luminous Intensity vs.
Ambient Temperature $(I_f = 20\text{mA})$



Spectrum Distribution $(T_a = 25^\circ\text{C})$



GL8HD4 (Red)

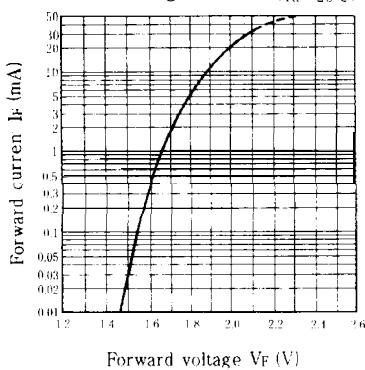
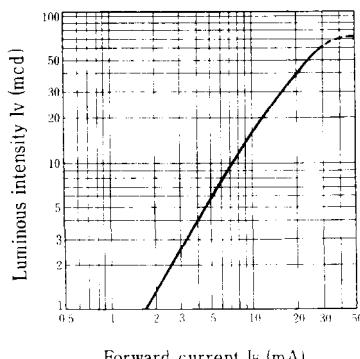
■ Electro-optical Characteristics

(Ta = 25°C)

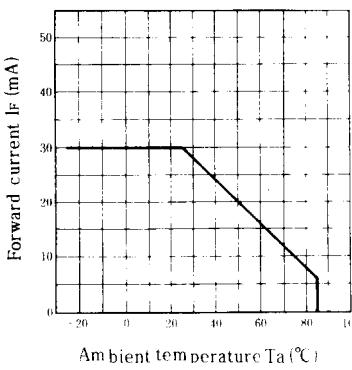
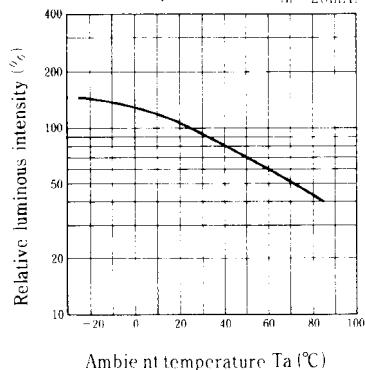
Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8HD4	I _F = 20mA		2.0	2.8	V
※3 Luminous intensity	I _V	GL8HD4	I _F = 20mA	15	40	-	mcd
Peak emission wavelength	λ_p	GL8HD4	I _F = 20mA		635	-	nm
Spectrum radiation bandwidth	$\Delta\lambda$	GL8HD4	I _F = 20mA		35	-	nm
Reverse current	I _R	GL8HD4	V _R = 4V		-	10	μA
Terminal capacitance	C _T	GL8HD4	V = 0V f = 1 MHz	-	20	--	pF
Response frequency	f _C	GL8HD4	-	-	4	-	MHz

※3 Tolerance: ±30%

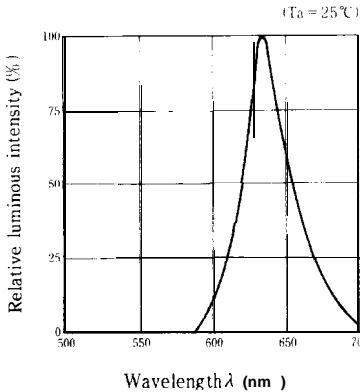
■ Characteristics Diagrams

Forward Current vs.
Forward Voltage
(Ta = 25°C)Luminous Intensity vs.
Forward Current
(Ta = 25°C)

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature
(I_F = 20mA)

Spectrum Distribution



GL8HY4 (Yellow)

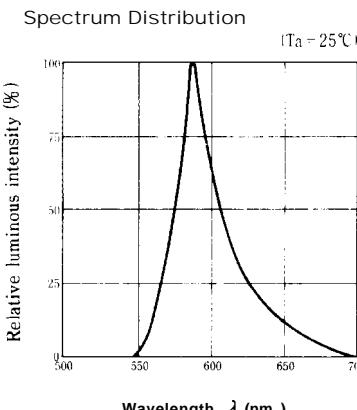
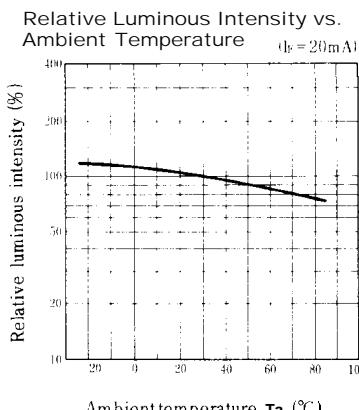
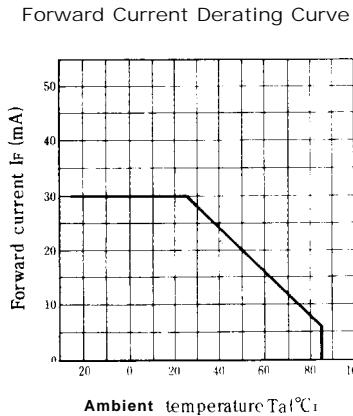
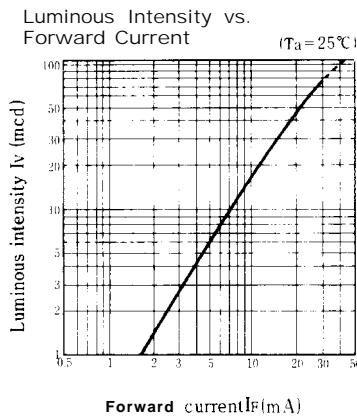
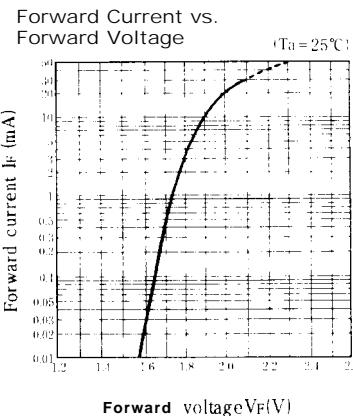
■ Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8HY4	I _F =20mA	—	2.0	2.8	V
*3 Luminous intensity	I _V	GL8HY4	I _F =20mA	14	44	—	mcd
Peak emission wavelength	λ_p	GL8HY4	I _F =20mA	—	585	—	nm
Spectrum radiation bandwidthb	$\Delta\lambda$	GL8HY4	I _F =20mA	—	30	—	nm
Reverse current	I _R	GL8HY4	V _R =4V	—	—	10	μA
Terminal capacitance	C _t	GL8HY4	V=0V f=1 MHz	—	35	—	pF
Response frequency	f _c	GL8HY4	—	—	4	—	MHz

*3 Tolerance: ±30%

■ Characteristics Diagrams



GL8EG4 (Yellow-green)

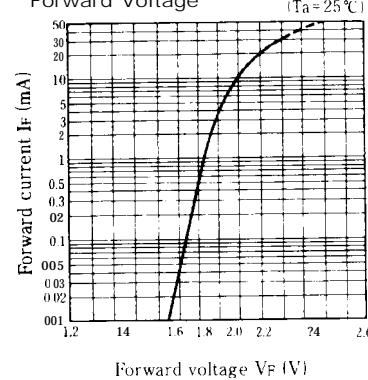
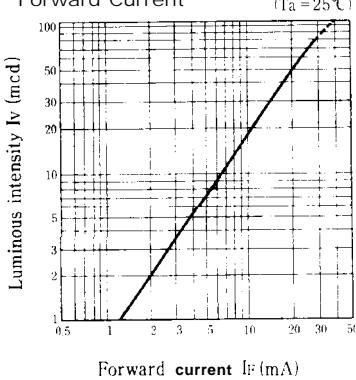
■ Electro-optical Characteristics

(Ta = 25°C)

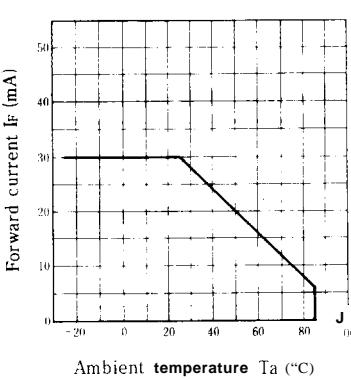
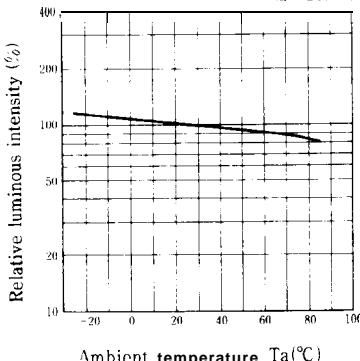
Parameter	Symbol	Model No.	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	GL8EG4	I _F = 20mA	—	2.1	2.8	V
※3 Luminous intensity	I _V	GL8EG4	I _F = 20mA	20	50	—	mcd
Peak emission wavelength	λ_p	GL8EG4	I _F = 20mA	—	565	—	nm
Spectrum radiation bandwidth	$\Delta\lambda$	GL8EG4	I _F = 20mA	—	30	—	nm
Reverse current	I _R	GL8EG4	V _R = 4V	—	—	10	μA
Terminal capacitance	C _t	GL8EG4	V=OV f=1 MHz	—	35	—	pF
Response frequency	f _c	GL8EG4	—	—	4	—	MHz

※3 Tolerance: ±30%

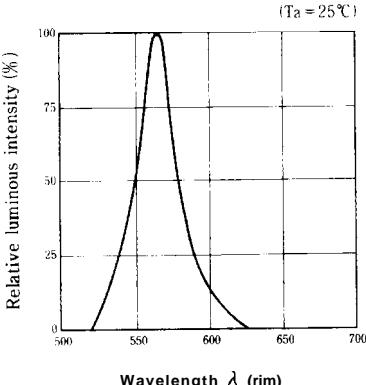
■ Characteristics Diagrams

Forward Current vs.
Forward VoltageLuminous Intensity vs.
Forward Current

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature (I_F = 20mA)

Spectrum Distribution



SHARP